

8/26/2008

PRODUCT RELIABILITY REPORT FOR

DS2784, Rev A4

Maxim Integrated Products

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Prepared by:

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Conclusion:

The following qualification successfully meets the quality and reliability standards required of all Maxim products:

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DS2784, Rev A4
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In addition, Maxim's continuous reliability monitor program ensures that all outgoing product will continue to meet Maxim's quality and reliability standards. The current status of the reliability monitor program can be viewed at http://www.maxim-ic.com/TechSupport /dsreliability.html.

Device Description:

A description of this device can be found in the product data sheet. You can find the product data sheet at http://dbserv.maxim-ic.com/l_datasheet3.cfm.

Reliability Derating:

The Arrhenius model will be used to determine the acceleration factor for failure mechanisms that are temperature accelerated.

AfT = exp((Ea/k)*(1/Tu - 1/Ts)) = tu/ts AfT = Acceleration factor due to Temperature tu = Time at use temperature (e.g. 55°C) ts = Time at stress temperature (e.g. 125°C) k = Boltzmann's Constant (8.617 x 10-5 eV/°K) Tu = Temperature at Use (°K) Ts = Temperature at Stress (°K) Ea = Activation Energy (e.g. 0.7 ev)

The activation energy of the failure mechanism is derived from either internal studies or industry accepted standards, or activation energy of 0.7ev will be used whenever actual failure mechanisms or their activation energies are unknown. All deratings will be done from the stress ambient temperature to the use ambient temperature.

An exponential model will be used to determine the acceleration factor for failure mechanisms, which are voltage accelerated.

AfV = exp(B*(Vs - Vu)) AfV = Acceleration factor due to Voltage Vs = Stress Voltage (e.g. 7.0 volts) Vu = Maximum Operating Voltage (e.g. 5.5 volts) B = Constant related to failure mechanism type (e.g. 1.0, 2.4, 2.7, etc.)

The Constant, B, related to the failure mechanism is derived from either internal studies or industry accepted standards, or a B of 1.0 will be used whenever actual failure mechanisms or their B are unknown. All deratings will be done from the stress voltage to the maximum operating voltage. Failure rate data from the operating life test is reported using a Chi-Squared statistical model at the 60% or 90% confidence level (Cf).

The failure rate, Fr, is related to the acceleration during life test by:

Fr = X/(ts * AfV * AfT * N * 2)X = Chi-Sq statistical upper limit N = Life test sample size Failure Rates are reported in FITs (Failures in Time) or MTTF (Mean Time To Failure). The FIT rate is related to MTTF by:

MTTF = 1/Fr

NOTE: MTTF is frequently used interchangeably with MTBF.

The calculated failure rate for this device/process is:

FAILURE RATE:	MTTF (YRS):	81715	FITS:	1.4
	DEVICE HOURS:	695424	FAILS:	0

Only data from Operating Life or similar stresses are used for this calculation.

The parameters used to calculate this failure rate are as follows:

Cf: 60%	Ea: 0.7	B: 0	Tu: 25 °C	Vu: 4.6 Volts
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The reliability data follows. At the start of this data is the device information. The next section is the detailed reliability data for each stress. The reliability data section includes the latest data available and may contain some generic data. "*" after DATE CODE denotes specific product data and SEQ No. to identify specific line items in the report for comments when required.

[Device	Information:	

Process:	E35XG-
	3P3M,GOI,DPE2,CrSi,DSD,PDESD,PDRES,Cap,ENPN,DPT,HTO,S
Passivation:	TEOS Ox-Nit Passivation for E35X; Full BEOL at SA; PT
	only in Dallas
Die Size:	98 x 129
Number of Transistors:	170939
Interconnect:	Aluminum / 0.5% Copper
Gate Oxide Thickness:	120 Å

ELECTRICAL CHARACTERIZATION

DESCRIPTION	DATE CODE/SEQ CONDITION		CONDITION	READPOINT		QTY	FAILS	FA#
ESD SENSITIVITY	0826	* 1	EOS/ESD S5.1 HBM 500 VOLTS	1	PUL'S	3	0	
ESD SENSITIVITY	0826	* 2	EOS/ESD S5.1 HBM 1000 VOLTS	1	PUL'S	3	0	
ESD SENSITIVITY	0826	* 3	EOS/ESD S5.1 HBM 2000 VOLTS	1	PUL'S	3	0	
ESD SENSITIVITY	0826	* 4	EOS/ESD S5.1 HBM 3000 VOLTS	1	PUL'S	3	0	
ESD SENSITIVITY	0826	* 5	EOS/ESD S5.1 HBM 4000 VOLTS	1	PUL'S	3	0	
LATCH-UP	0826	* 6	JESD78, I-TEST 125C			6	0	
LATCH-UP	0826	* 7	JESD78, V-SUPPLY TEST 125C			6	0	
					Total:		0	

OPERATING LIFE

DESCRIPTION	DATE CODE/SEQ	CONDITION	READPOINT	QTY Ι	FAILS	FA#
HIGH TEMP OP LIFE	0640	125C, 5.5 VOLTS	1000 HRS	45	0	
HIGH TEMP OP LIFE	0642	125C, 5.5 VOLTS	1000 HRS	45	0	
HIGH TEMP OP LIFE	0714	125C, 5.5 V (PSA) & 15.0 V (PSB)	1000 HRS	77	0	
HIGH TEMP OP LIFE	0723	125C, 5.5 VOLTS	1000 HRS	45	0	

HIGH TEMP OP LIFE	0727	125C, 5.5 VOLTS	1000 HRS	77	0
HIGH TEMP OP LIFE	0732	125C, 5.5 V (PSA) & 15.0 V (PSB)	1000 HRS	77	0
HIGH TEMP OP LIFE	0736	125C, 5.5 VOLTS	1000 HRS	77	0
HIGH TEMP OP LIFE	0744	125C, 5.5 VOLTS	1000 HRS	77	0
HIGH TEMP OP LIFE	0749	125C, 5.5 VOLTS	1000 HRS	75	0
HIGH TEMP OP LIFE	0804	125C, 5.5 VOLTS	1000 HRS	77	0
HIGH TEMP OP LIFE	0824	125C, 5.5 VOLTS	192 HRS	45	0
HIGH TEMP OP LIFE	0826 * 1	125C, 5.5 V (PSA) & 15.0 V (PSB)	192 HRS	77	0
			Total:		0

DESCRIPTION	DATE C	ODE/SEQ	CONDITIO	N		READ	POINT	QTY	FAILS	FA#
WRITE CYCLE STRESS (KCYS)	0640		70 C, 5.5 V	OLTS		50	KCYS	77	0	
STORAGE LIFE	0640	0640				1000	HRS	77	0	
WRITE CYCLE STRESS (KCYS)	0642		50 C, 5.5 ∖ (PSB)	/OLTS (PSA), 15	0 VOLTS	10	KCYS	77	0	
STORAGE LIFE	0642		150C			1000	HRS	77	0	
WRITE CYCLE STRESS (KCYS)	0642		50 C, 5.5 ∖ (PSB)	/OLTS (PSA), 15	0 VOLTS	1	KCYS	77	0	
STORAGE LIFE	0642		150C			1000	HRS	77	0	
WRITE CYCLE STRESS (CYS)	0642		50 C, 5.5 V (PSB)	/OLTS (PSA), 15.	0 VOLTS	100	CYS	77	0	
STORAGE LIFE	0642		150C			1000	HRS	77	0	
WRITE CYCLE STRESS (KCYS)	0714		50 C, 5.5 \	/ (PSA) & 15.0 V	(PSB)	50	KCYS	77	0	
STORAGE LIFE	0714		150C			1000	HRS	77	0	
WRITE CYCLE STRESS (KCYS)	0732		50 C, 5.5 \	/ (PSA) & 15.0 V	(PSB)	50	KCYS	77	0	
STORAGE LIFE	0732		150C			1000	HRS	77	0	
WRITE CYCLE STRESS (KCYS)	0736		50 C, 5.5 V	OLTS		50	KCYS	77	0	
STORAGE LIFE	0736		150C			1000	HRS	77	0	
WRITE CYCLE STRESS (CYS)	0824		50 C, 5.5 V (PSB)	/OLTS (PSA), 15	0 VOLTS	100	CYS	77	0	
STORAGE LIFE	0824		150C			96	HRS	77	0	
WRITE CYCLE STRESS (KCYS)	0826	* 2	50 C, 5.5 \	/ (PSA) & 15.0 V	(PSB)	50	KCYS	77	0	
STORAGE LIFE	0826	* 2	150C			96	HRS	77	0	
						-	Total:		0	
FAILURE RATE:		MTTF	(YRS):	81715	FITS:		1.4			
	DE	EVICE H	OURS:	695424	FAILS:		0			